

Major Ratings and Characteristics

| | |
|--------------------|-----------------------|
| $I_{F(AV)}$ | 1.0 A |
| V_{RRM} | 50 V to 1000 V |
| I_{FSM} | 30 A |
| t_{rr} | 50 nS , 75 nS |
| V_F | 1.0 V , 1.3 V , 1.7 V |
| $T_j \text{ max.}$ | 150 °C |

Features

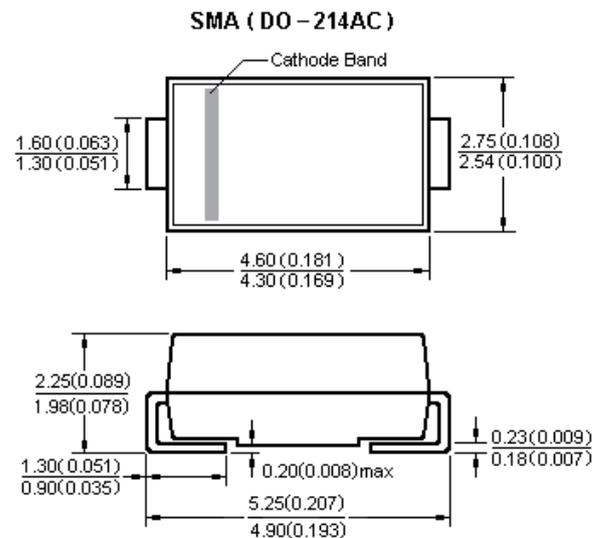
- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- Ultrafast reverse recovery time
- Low switching losses, high efficiency
- High forward surge capability
- High temperature soldering:
260°C/10 seconds at terminals
- Component in accordance to
RoHS 2002/95/1 and WEEE 2002/96/EC

Mechanical Date

- Case: JEDEC DO-214AC molded plastic body over passivated chip
- Terminals: Solder plated, solderable per J-STD-002B and JESD22-B102D
- Polarity: Laser band denotes cathode end



SMA (DO-214AC)



Dimensions in millimeters and (inches)

Maximum Ratings & Thermal Characteristics & Electrical Characteristics

(TA = 25 °C unless otherwise noted)

| | Symbol | (US1A) | (US1B) | (US1D) | (US1G) | (US1J) | (US1K) | (US1M) | UNIT |
|---|-----------------|-------------|--------|--------|--------|--------|--------|--------|---------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum RMS voltage | V_{RMS} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| Maximum average forward rectified current | $I_{F(AV)}$ | 1 | | | | | | | A |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | I_{FSM} | 30 | | | | | | | A |
| Maximum instantaneous forward voltage at 1.0A | V_F | 1.0 | | 1.3 | 1.7 | | | V | |
| Maximum DC reverse current at Rated DC blocking voltage | I_R | 5.0 | | | | | | | μ A |
| | | 50 | | | | | | | μ A |
| Maximum reverse recovery time at $I_F = 0.5 \text{ A}$, $I_R = 1.0 \text{ A}$, $I_{rr} = 0.25 \text{ A}$ | t_{rr} | 50 | | | | 75 | | | nS |
| Typical junction capacitance at 4.0 V , 1MHz | C_J | 15 | | | | 10 | | | pF |
| Thermal resistance from junction to ambient | $R_{\theta JA}$ | 75 | | | | | | | °C/W |
| Operating junction and storage temperature range | T_J, T_{STG} | -55 to +150 | | | | | | | °C |

(US1A~US1M) SMA

High Efficiency Recovery rectifiers

Characteristic Curves ($T_A=25\text{ }^\circ\text{C}$ unless otherwise noted)

Fig.1 Forward Current Derating Curve

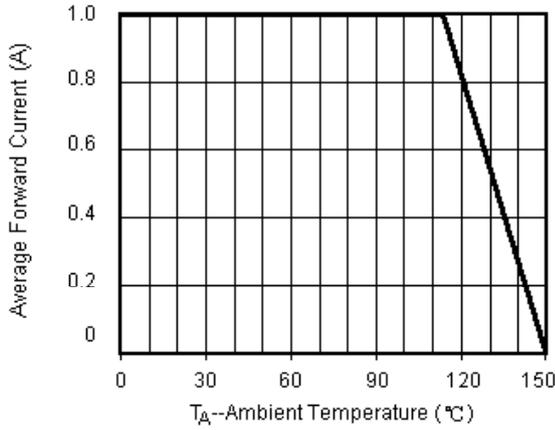


Fig.2 Maximum Non-Repetitive Peak Forward Surge Current

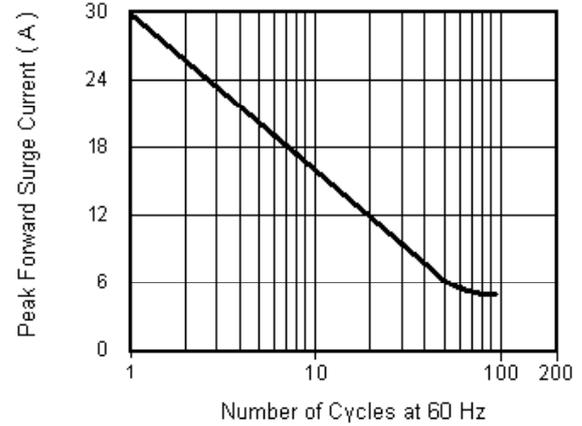


Fig.3 Typical Instantaneous Forward Characteristics

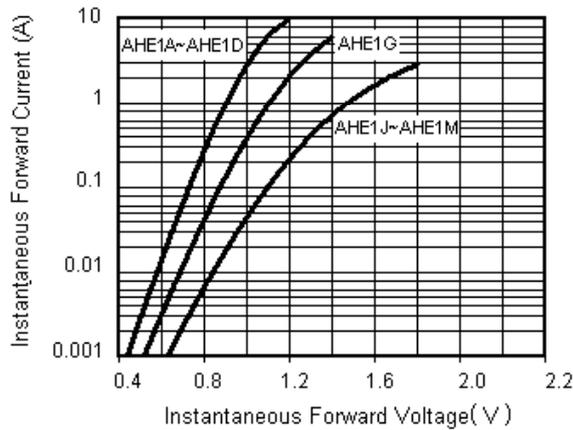


Fig.4 Typical Reverse Leakage Characteristics

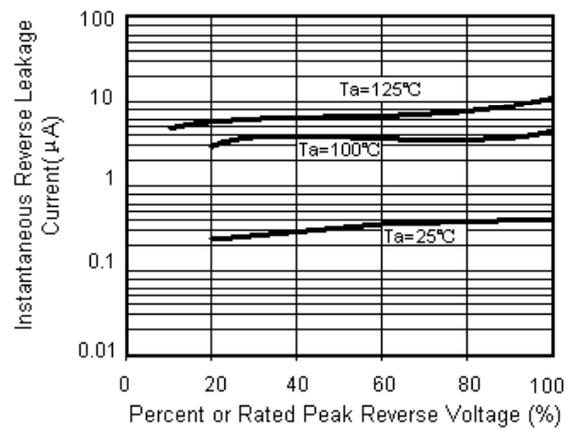


Fig.5 Typical Junction Capacitance

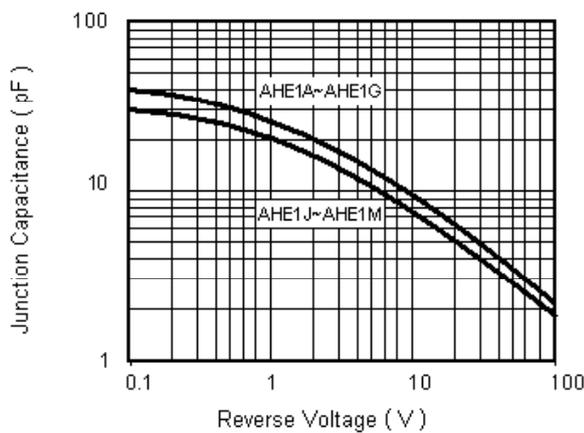


Fig.6 Transient Thermal Impedance

